

2955-2

T-52-17

HIGH-CURRENT HALF-BRIDGE POWER DRIVER

The UDN2955W-2 half-bridge power driver combines a high-current, half-bridge power driver with low-level control and protection circuitry. For PWM applications there are provisions for output current sensing and an ENABLE (active low) input. The output can source or sink up to 6 A continuously. This device features a minimum breakdown and sustaining voltage of 40 V. It can be used in pairs for full-bridge operation or in triplets for 3-phase brushless dc motors.

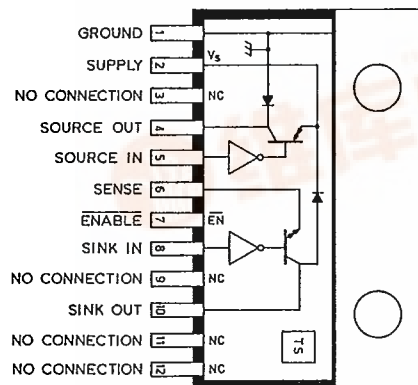
Protection is included which shuts down the device during over-temperature conditions caused by loss of cooling; internal flyback and clamp diodes are included for switching inductive loads. Internal logic lockout and delays prevent potentially destructive crossover currents. The logic inputs are compatible with TTL and 5 V CMOS logic systems.

A similar device, excluding the ENABLE and output current sensing provision, in a 5-lead TO-220 style package, is the UDN2951Z-2.

The UDN2955W-2 is supplied in a 12-lead power-tab single in-line plastic package. The tab is at ground potential, allowing multiple devices to share a common heat sink.

FEATURES

- ± 6 A Continuous Output Current
- Output Voltage to 40 V
- Internal Thermal Shutdown
- TTL and 5 V CMOS Compatible Inputs
- Integral Transient-Suppression Diodes



Dwg. PP-023

ABSOLUTE MAXIMUM RATINGS at $T_j \leq 150^\circ\text{C}$

Supply Voltage, V_S	40 V
Output Current, I_{OUT}	± 6.0 A
Input Voltage, V_{IN}	7.0 V
Sense Voltage, V_{SENSE}	1.5 V
Package Power Dissipation, P_D	See Graph
Operating Temperature Range, T_A	-20°C to $+85^\circ\text{C}$
Storage Temperature Range, T_S	-55°C to $+150^\circ\text{C}$

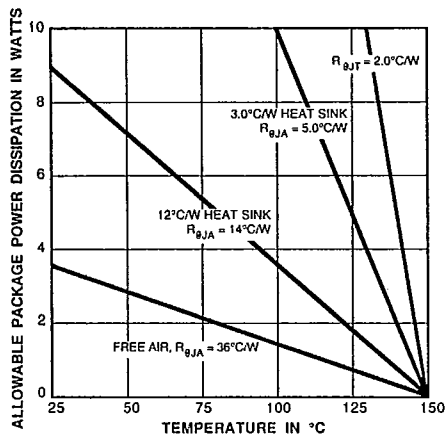
Output current rating may be limited by duty cycle, ambient temperature, and heat sinking. Under any set of conditions, do not exceed the specified output current rating or a junction temperature of $+150^\circ\text{C}$.

Always order by complete part number: **UDN2955W-2**.

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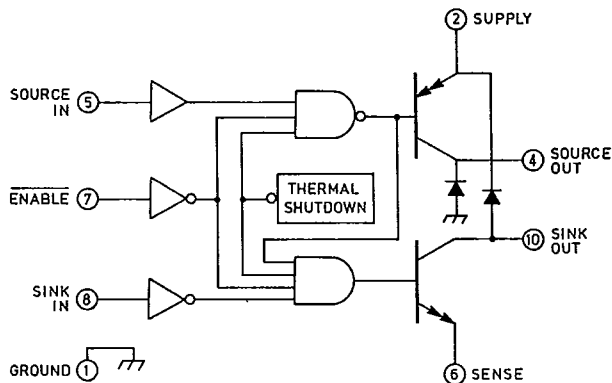
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Dwg. GP-012A

FUNCTIONAL BLOCK DIAGRAM



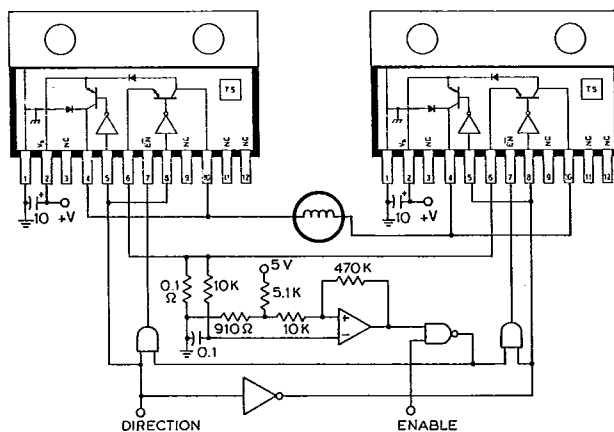
Dwg. FP-009

TRUTH TABLE

ENABLE	INPUTS		OUTPUTS	
	SOURCE	SINK	SOURCE	SINK
Low	Low	Low	OFF	ON
Low	Low	High	OFF	OFF
Low	High	X	ON	OFF
High	X	X	OFF	OFF

X = Irrelevant

TYPICAL APPLICATION



The printed wiring board should utilize a heavy ground plane. For optimum performance, the driver should be soldered directly into the board. The power supply (V_S) should be decoupled with an electrolytic capacitor ($\geq 10 \mu\text{F}$) as close as possible to pin 2.

Dwg. EP-019A

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ELECTRICAL CHARACTERISTICS at $T_A = +25^\circ\text{C}$, $T_J \leq +150^\circ\text{C}$, $V_S = 40\text{ V}$

Characteristic	Symbol	Test Conditions	Limits			
			Min.	Typ.	Max.	Units
Functional Supply Range	V_S		10	—	40	V
Output Leakage Current	I_{CEX}	SINK _{OUT} = 40 V, SOURCE _{IN} = 0.8 V, SINK _{IN} = 2.0 V	—	<1.0	50	μA
		SOURCE _{OUT} = 0 V, SOURCE _{IN} = 0.8 V, SINK _{IN} = 2.0 V	—	<-1.0	-50	μA
Output Sustaining Voltage	$V_{CE(sus)}$	$I_{OUT} = \pm 6.0\text{ A}$, $L = 10\text{ mH}$	40	—	—	V
Output Saturation Voltage	$V_{CE(SAT)}$	SINK _{OUT} = 5.0 A	—	—	1.5	V
		SINK _{OUT} = 6.0 A	—	—	2.0	V
		SOURCE _{OUT} = -5.0 A	—	—	2.0	V
		SOURCE _{OUT} = -6.0 A	—	—	2.5	V
Input Voltage	Logic 1	SOURCE _{IN} or SINK _{IN}	2.0	—	—	V
	Logic 0	SOURCE _{IN} or SINK _{IN}	—	—	0.8	V
Input Current	Logic 1	SOURCE _{IN} or SINK _{IN} = 2.0 V	—	3.0	10	μA
	Logic 0	SOURCE _{IN} or SINK _{IN} = 0.8 V	—	-1.0	-10	μA
Propagation Delay	t_{PHL}	Sink Driver (includes Turn-On Delay)	—	2.5	—	μs
		Source Driver	—	2.5	—	μs
	t_{PLH}	Sink Driver	—	0.2	—	μs
		Source Driver (includes Turn-On Delay)	—	2.5	—	μs
Supply Current	$I_{S(ON)}$	SOURCE _{IN} = 2.0 V	—	10	15	mA
		SOURCE _{IN} = SINK _{IN} = 0.8 V	—	20	25	mA
	$I_{S(OFF)}$	SOURCE _{IN} = 0.8 V, SINK _{IN} = 2.0 V	—	8.0	10	mA
Flyback Diode Forward Voltage	V_F	$I_F = 6.0\text{ A}$	—	—	2.8	V
Clamp Diode Forward Voltage	V_F	$I_F = 6.0\text{ A}$	—	—	2.1	V
Diode Leakage Current	I_R	Each Diode, $V_R = 40\text{ V}$	—	<1.0	50	μA
Thermal Shutdown	T_J		—	165	—	$^\circ\text{C}$

NOTE: Typical Data is given for circuit design information only.

Negative current is defined as coming out of (sourcing) the specified device pin.